

View Online at <https://aerobasegroup.com/nsn/5961-00-905-2719>

Inclosure Material:

Metal all transistor

Overall Length:

1.803 inches all transistor

Mounting Facility Quantity:

1 all transistor

Internal Configuration:

Junction contact all transistor

Electrode Internally-electrically Connected To Case:

Collector all transistor

Internal Junction Configuration:

Npn all transistor

Component Function Relationship:

Matched

Component Name And Quantity:

2 transistor

Mounting Method:

Threaded stud all transistor

Overall Width Across Flats:

0.875 inches all transistor

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage/static/emitter open all transistor and 100.0 collector to emitter voltage/static/base open all transistor and 15.0 emitter to base voltage, static, collector open all transistor

Current Rating Per Characteristic:

7.50 amperes source cutoff current all transistor and 30.00 amperes source cutoff current all transistor

Power Rating Per Characteristic:

200.0 watts small-signal input power, common-collector preset all transistor

Maximum Operating Temperature Per Measurement Point:

175.0 degrees celsius junction all transistor

Terminal Type And Quantity:

1 threaded stud all transistor and 2 tab, solder lug all transistor

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0